Storage Temperature Range



EMK13 H 2 H -41.666M

Frequency Tolerance/Stability ±50ppm Maximum over -40°C to +85°C Duty Cycle -50 ±5(%)

-55°C to +125°C

- Iri-Stati

Nominal Frequency 41.666MHz

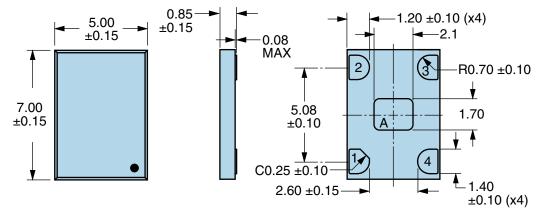
Output Control Function
 Tri-State (Disabled Output: High Impedance)

ELECTRICAL SPECIFICATIONS		
Nominal Frequency	41.666MHz	
Frequency Tolerance/Stability	±50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration)	
Aging at 25°C	±1ppm Maximum First Year	
Operating Temperature Range	-40°C to +85°C	
Supply Voltage	3.3Vdc ±10%	
Input Current	25mA Maximum	
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH=-8mA)	
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL=+8mA)	
Rise/Fall Time	2nSec Maximum (Measured from 20% to 80% of waveform)	
Duty Cycle	50 ±5(%) (Measured at 50% of waveform)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Output Control Function	Tri-State (Disabled Output: High Impedance)	
Output Control Input Voltage	+0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output	
Peak to Peak Jitter (tPK)	250pSec Maximum, 100pSec Typical	
Start Up Time	50mSec Maximum	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V	
Flammability	UL94-V0	
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity Level	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only)	
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Thermal Shock	MIL-STD-883, Method 1011, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A, 20G	



MECHANICAL DIMENSIONS (all dimensions in millimeters)



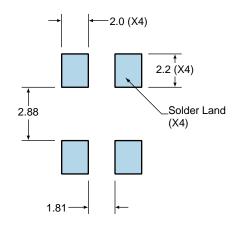
Note A: Center paddle is connected internally to oscillator ground (Pad 2).

PIN CONNECTION 1 Tri-State (High Impedance) 1 Power Down (Logic Low) 2 Ground 3 Output 4 Supply Voltage

LINE	MARKING
1	XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code

Suggested Solder Pad Layout

All Dimensions in Millimeters



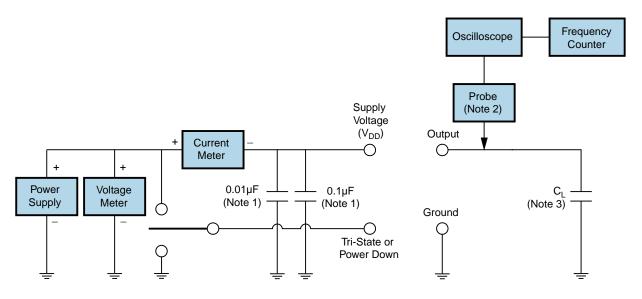
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



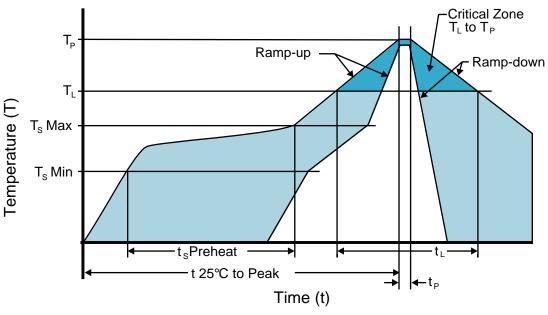
Test Circuit for CMOS Output



- Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _S MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _s MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T _L)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.